

# **Rewritable holographic memory**

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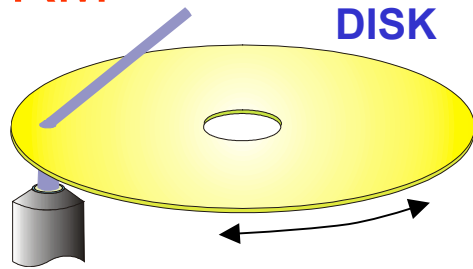
**Pasadena, CA 91125**

# Outline

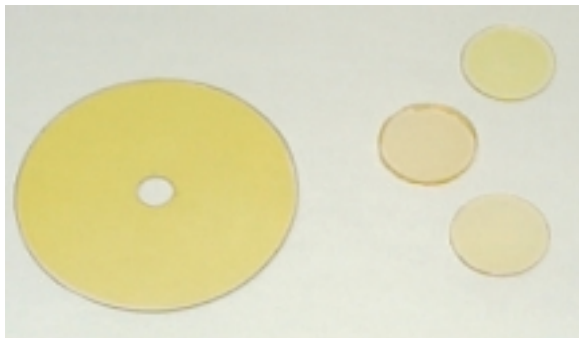
- **Rewritable versus ROM/WORM holographic memories**
- **Can holographic memories replace magnetic disks?**
- **Compact HRAM module**
- **Recording material**

# Holographic Memory

ROM/WORM

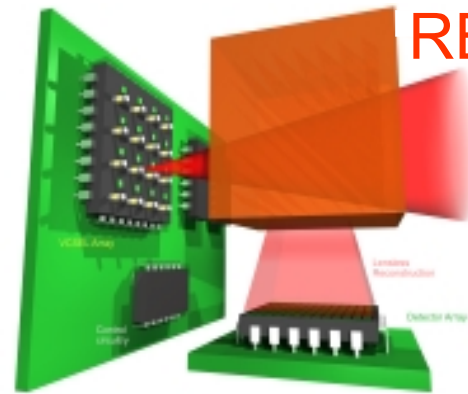


DISK



Photopolymers

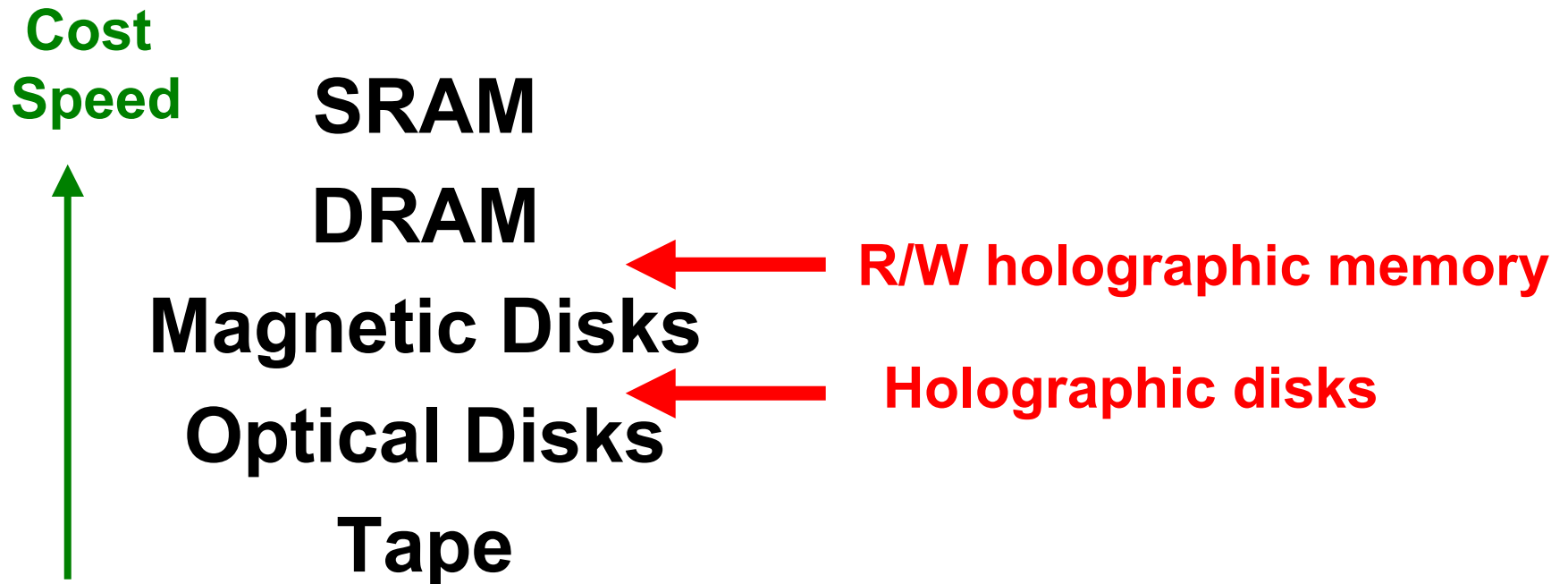
REWRITABLE



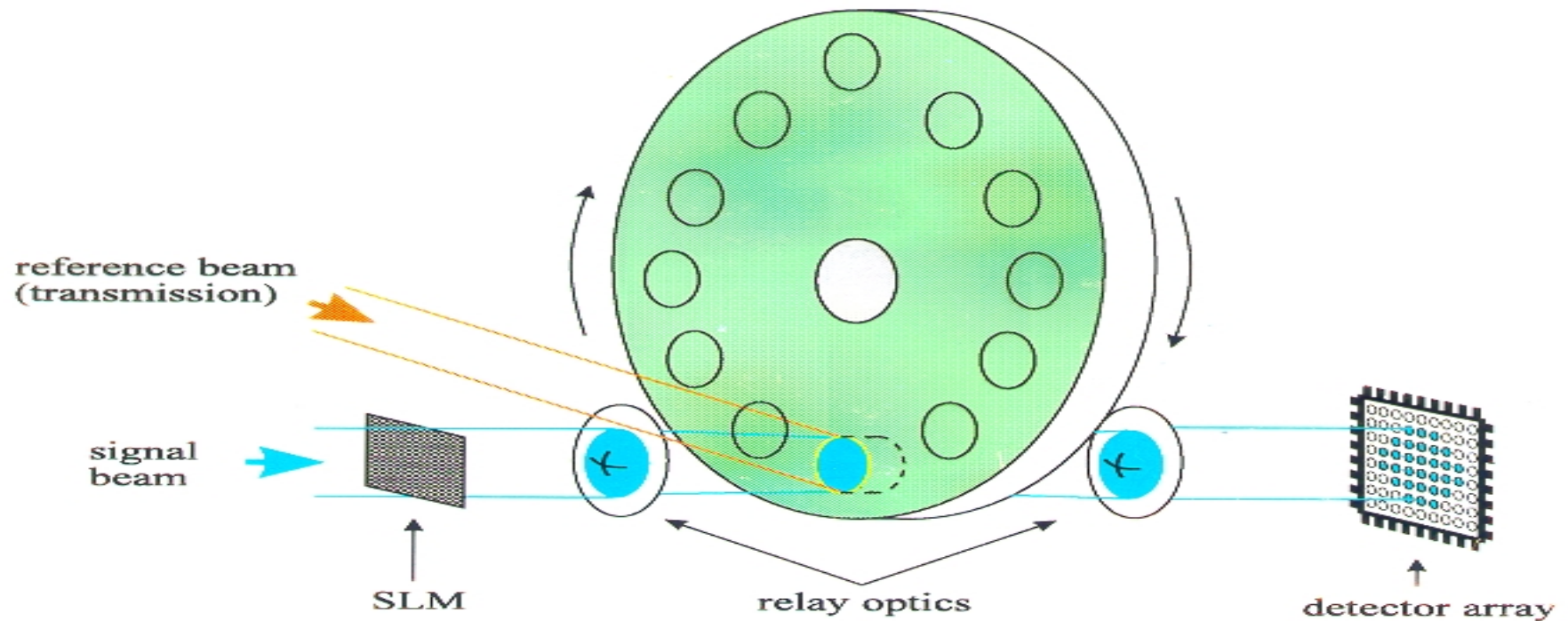
Photorefractives



# Memory Hierarchy

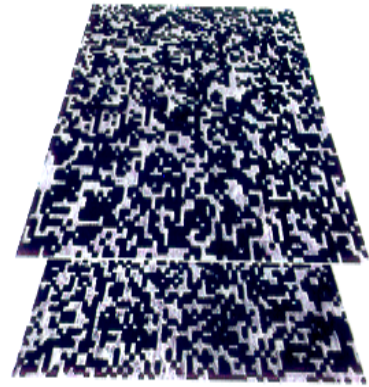


# Holographic 3-D Disk





### Stack of 32 Holograms

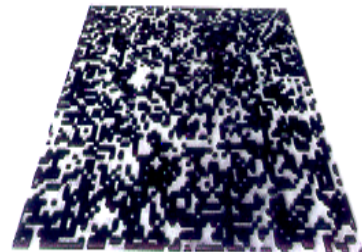


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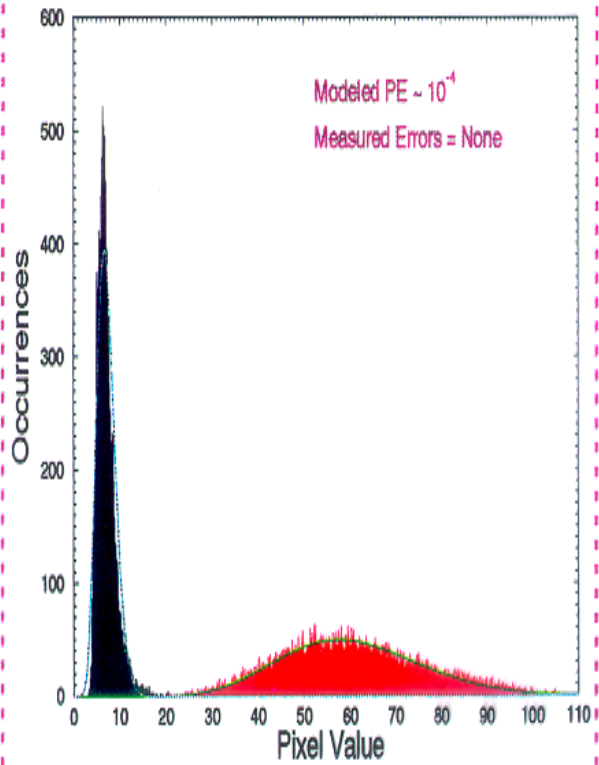
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### Combined Histogram of the 32 Reconstructions

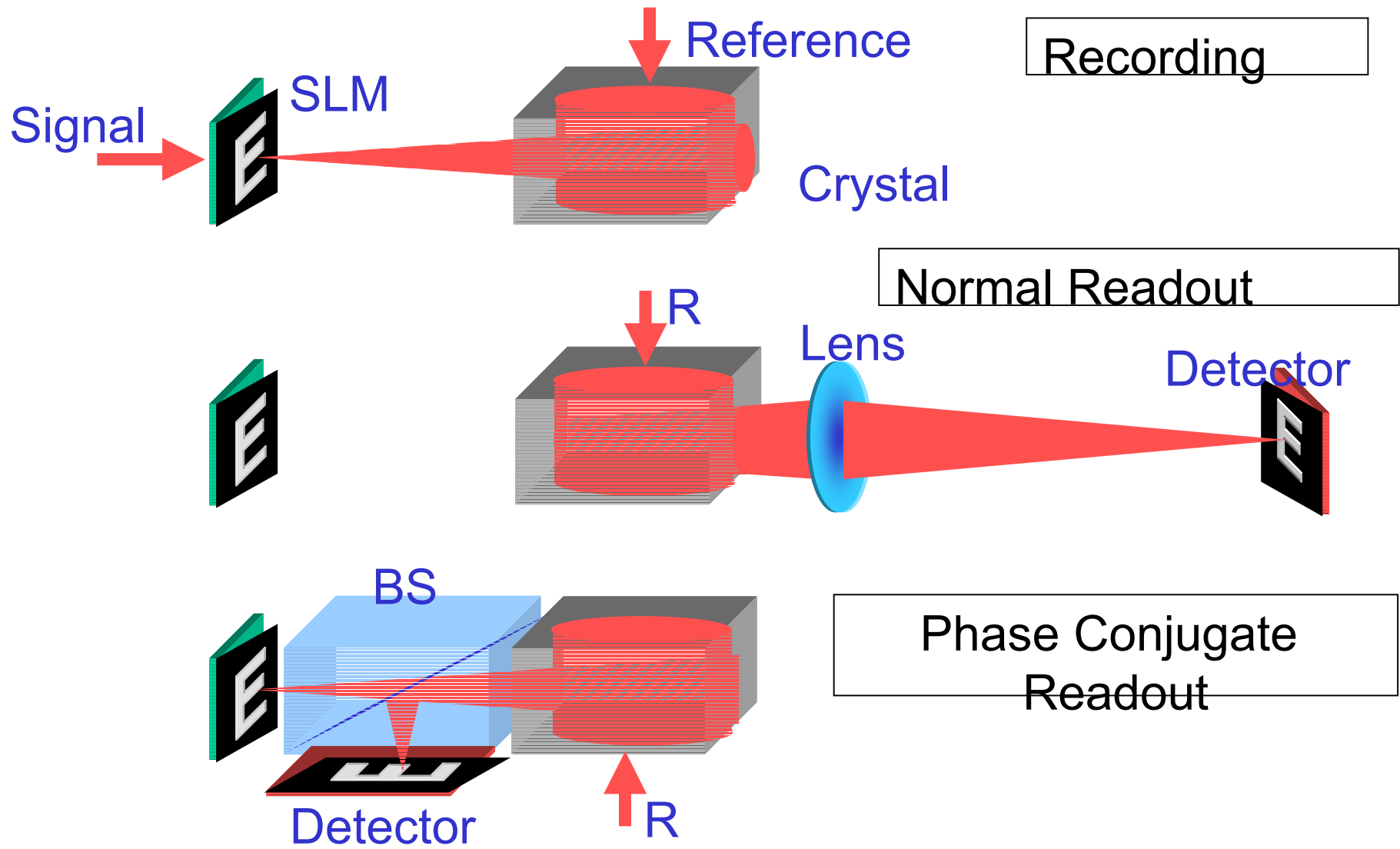
9 65x65 pixels windows sampled from the 32 reconstructions



# Rewritable holographic memories should be:

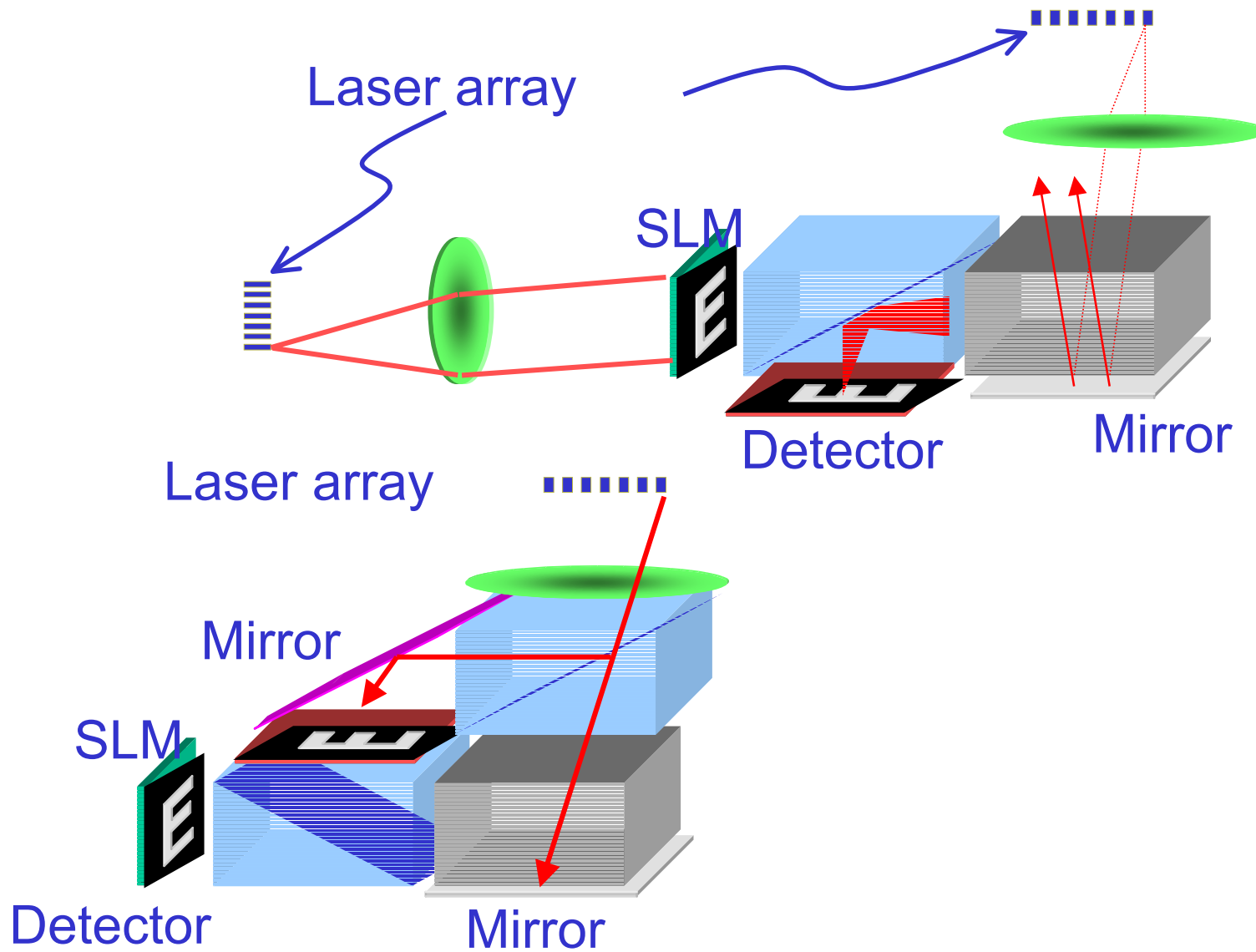
- **Faster** than magnetic disks
- **Cheaper** than DRAM

# Phase Conjugate Readout

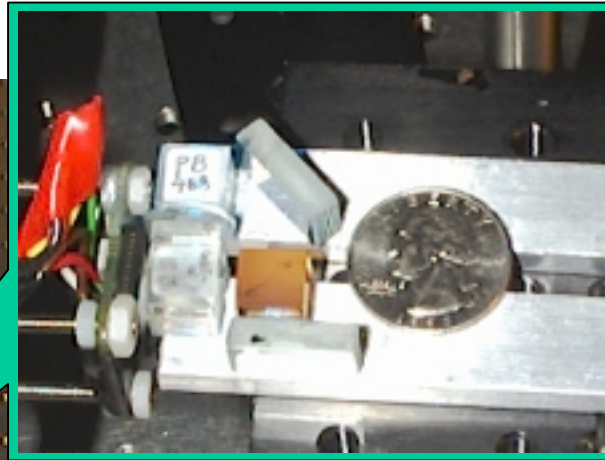
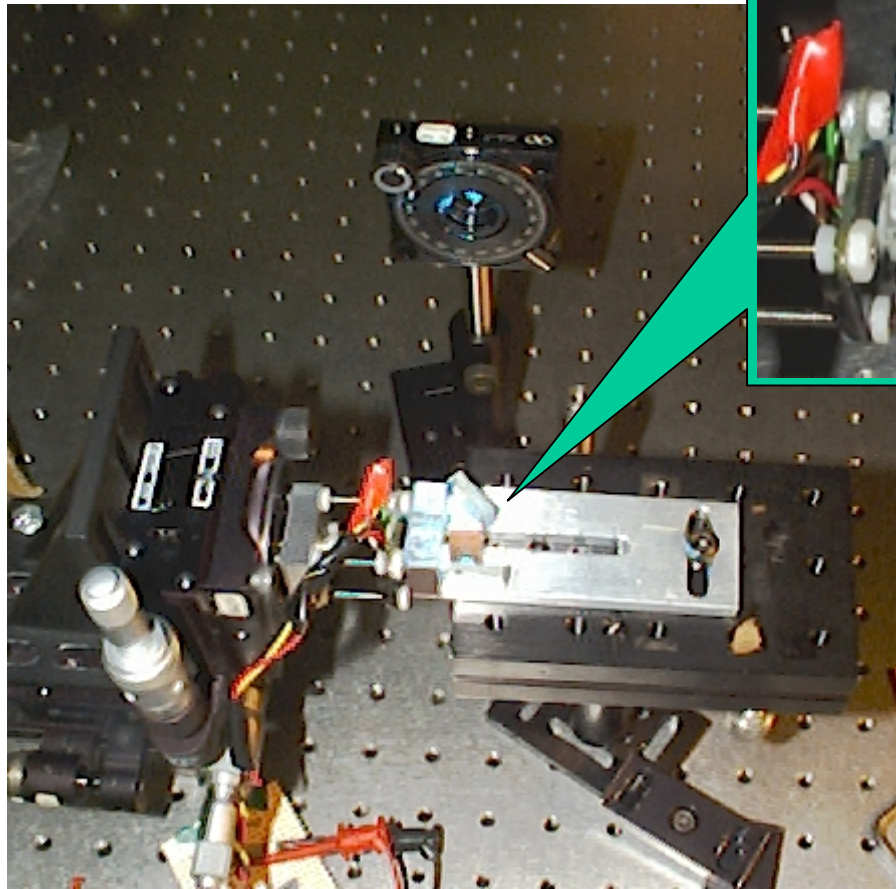




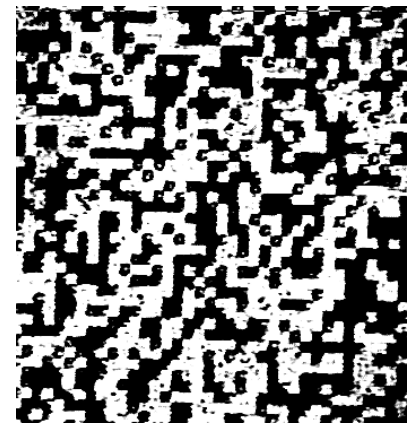
# Holographic Multiplexing and Compact Module



# Demo Setup and Reconstruction



**2x2 mm<sup>2</sup> pixels**



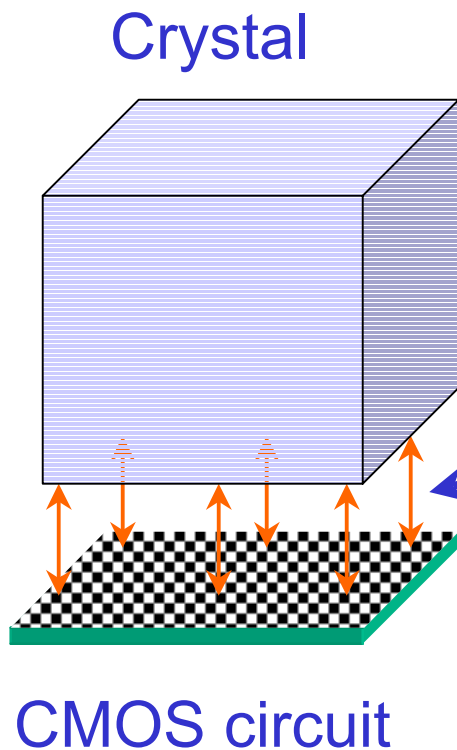
# HRAM random access time

## Photon budget

- number of pixels  $N=3,000$
- laser power  $I=100$  mW
- medium  $M/10$
- number of holograms  $M=1,000$
- number of photons  $N_p=300$

$$\tau = \frac{h\nu N_p M^2 N^2}{I \cdot (M/\#)^2} < 100 \mu s$$

# Recording and Readout Rate



$$\text{Recording Rate} = \frac{N^2}{\tau_{\text{record}}}$$

$$\text{Readout Rate} = \frac{N^2}{\tau_{\text{read}}}$$

$$\tau_{\text{record}} = 100 \text{ msec}, \quad \tau_{\text{read}} = 100 \mu\text{sec}$$

$N^2$  channels

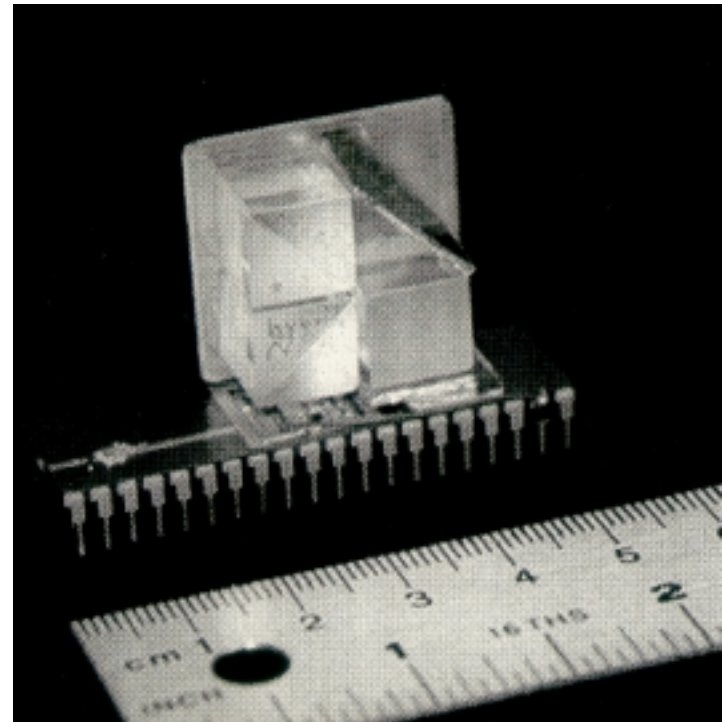
For  $N^2 = 8 \times 10^6 = 1 \text{ MB}$ ,

Recording: 10 MB/sec

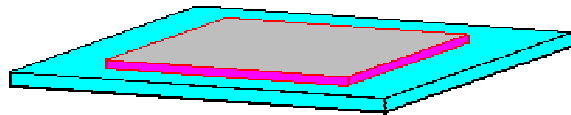
Readout: 10 GB/sec

# HRAM Module

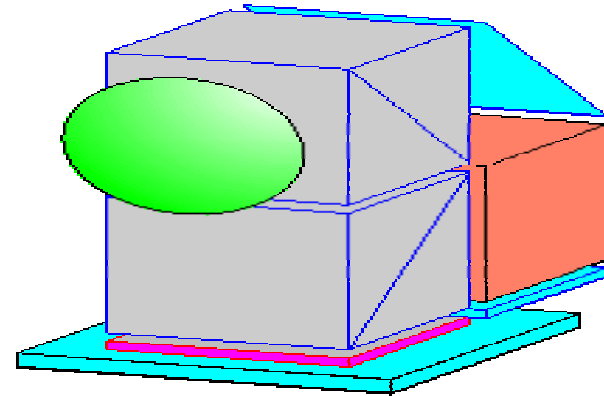
Capacity	<b>1 GB</b>
Access time	<b>100<math>\mu</math>s</b>
Recording bandwidth	<b>10 MB/s</b>
Readout bandwidth	<b>10GB/s</b>
Size (cm)	<b>1x2x2</b>



# Cost Comparison



DRAM



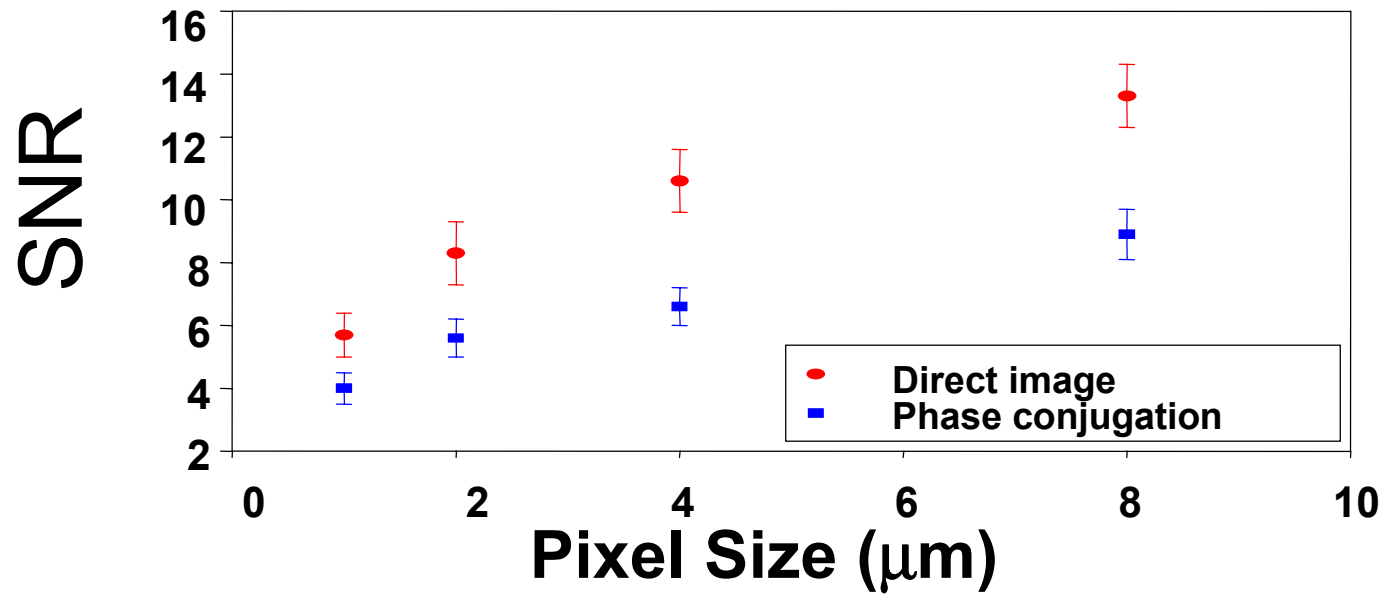
HRAM(M pages)

$$\frac{\text{Cost of HRAM}}{\text{Cost of DRAM}} = \underbrace{\frac{\text{Cost}_{\text{optics}} + \text{Cost}_{\text{si}}}{\text{Cost}_{\text{si}}}}_{\approx 2} \cdot \underbrace{\frac{\text{SLM pixel area}}{\text{DRAM cell area}}}_{25} \cdot \frac{1}{M} = \frac{1}{20}$$

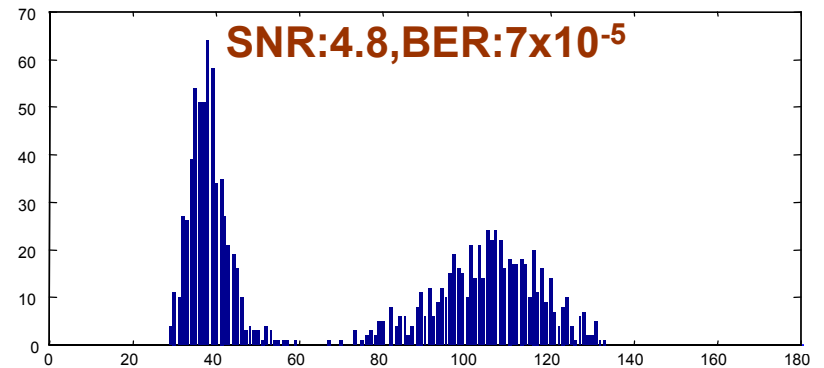
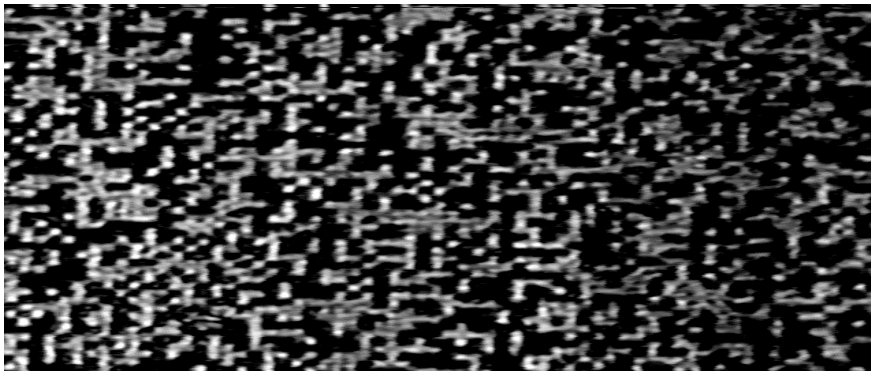
$\downarrow$   
 $10^{-3}$

	1998	2006
DRAM cell(/bit)	1 x 1 $\mu\text{m}^2$	0.04 $\mu\text{m}^2$
HRAM pixel(/bit)	5 x 5 $\mu\text{m}^2$	1 x 1 $\mu\text{m}^2$

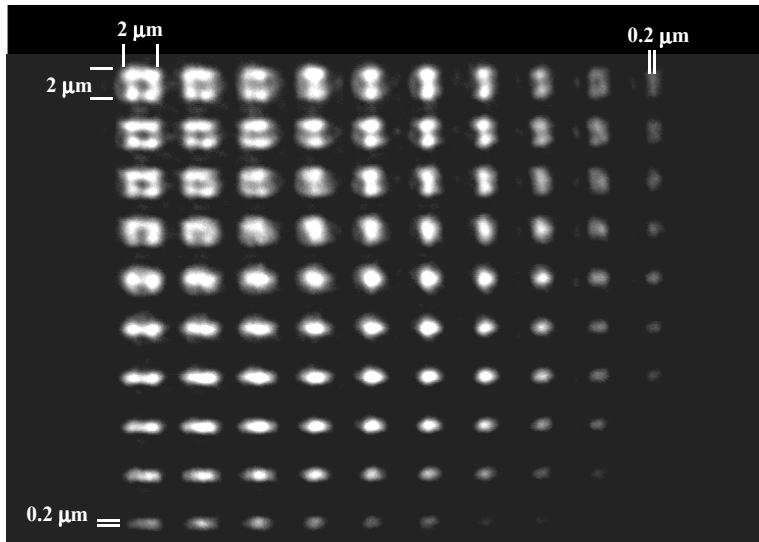
# SNR vs. Pixel Size



**1x1 $\mu\text{m}^2$  pixel reconstruction**

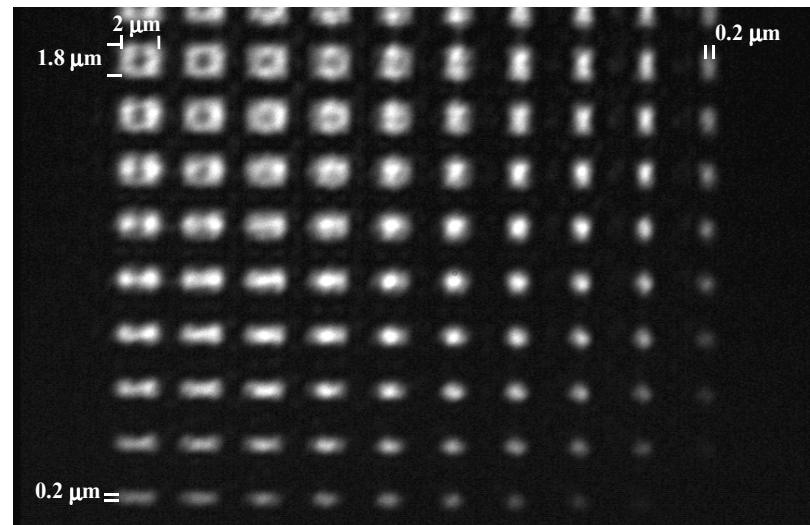


# Mask With Various Pixel Sizes



Microscope image:  
(Nikon lens, NA0.65)

Phase Conjugate  
Reconstruction:  
(Nikon lens, NA 0.65)





# Components

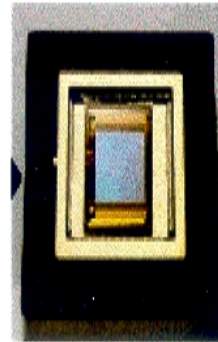
- SLM

MicroDisplay: 1024x768,  
pitch 12.5 micron  
frame rate: 30-180 Hz



- Detector

Photobit: 1040x1040  
pitch: 10 micron  
frame rate: 500 Hz



- Laser diode

SDL: 30 mW, 630nm



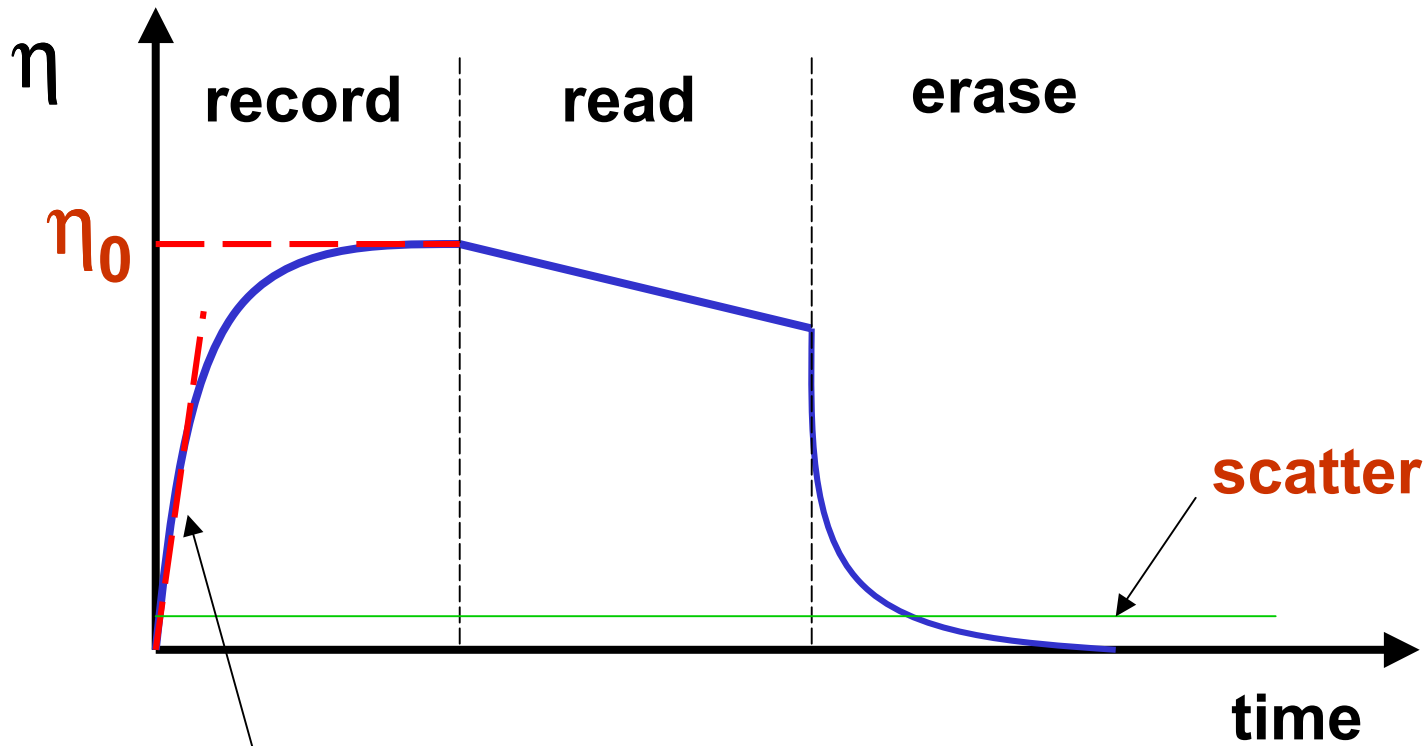
# HRAM components

	Currently available	Requirement ( 1 GB module)
SLM	1000x1000 10 $\mu\text{m}$	3000x3000 3 $\mu\text{m}$
Detector	1000x1000 5 $\mu\text{m}$	3000x3000 3 $\mu\text{m}$
Laser	Single laser plus mechanical scanning	Laser array or wavelength tunable
Material	M/1, S=0.1cm/J, Volatile, non-persistent	M/10, S=1cm/J Nonvolatile, persistent

# Multiplexing Laser

	<b>Pro</b>	<b>Con</b>
<b>VCSEL array</b>	<b>Fast switching</b>	<b>Low power</b>
<b>Electrically tunable laser diode</b>	<b>Simple; compact</b>	<b>Availability at visible wavelength; cost</b>
<b>Single laser plus MEMS scanning</b>	<b>High power</b>	<b>Speed ?</b>
<b>Hybrid (eg. 100 lasers + MEMS, one or multiple wavelengths)</b>	<b>High power, Fast scanning</b>	<b>Expensive? Bulky?</b>

# Recording and erasure characteristics



**Sensitivity**

$$S = \frac{d\sqrt{\eta}/dt}{IL} \quad (\text{cm/J})$$

$$\eta = \left( \frac{M / \#}{M} \right)^2$$

$$M / \# = \frac{\sqrt{\eta_0} \tau_e}{\tau_w}$$

# Material Requirements

**Resolution:**

pixel size < 3  $\mu\text{m}$

**Sensitivity:**

**S=1 cm/J**

recording time = 100 msec

@ I= 100 mW/cm<sup>2</sup>

**Dynamic range:**

**M/#=10**

read-out time = 100  $\mu\text{sec}$

@ M=1,000 holograms

**Persistence:**

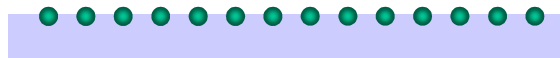
decay time > 100,000 sec

**Conduction band**



**Valence band**

**Conduction band**

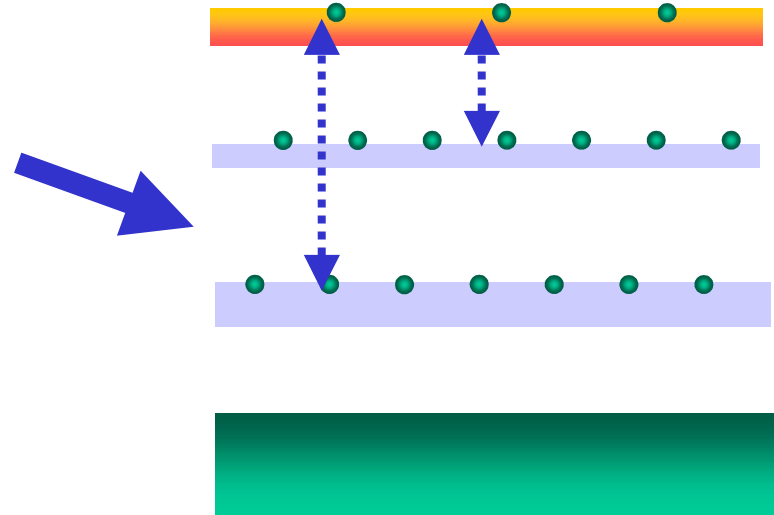


**Valence band**

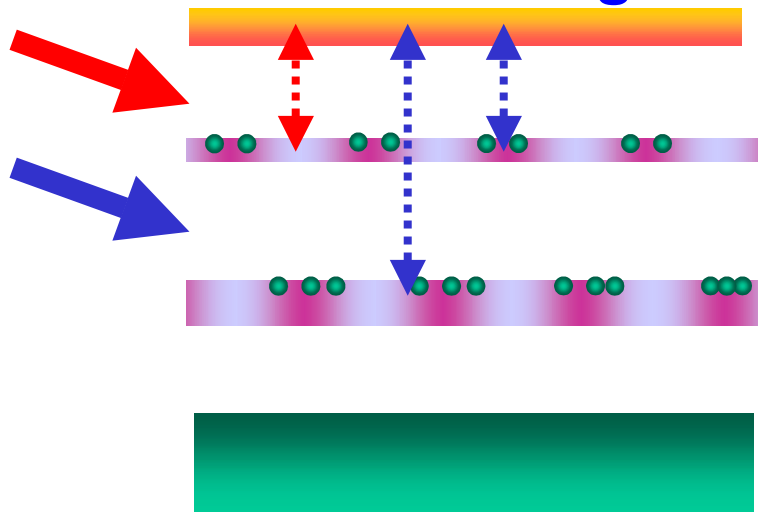
### Initial condition



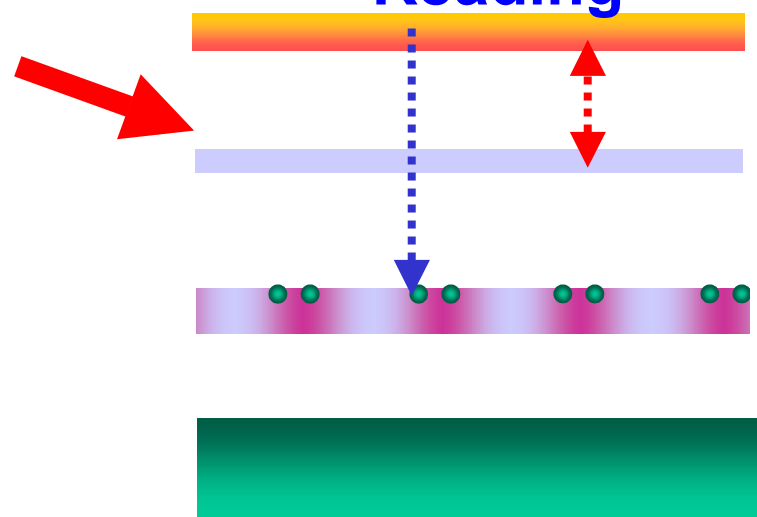
### Sensitization



### Recording



### Reading



# Conclusion

- Small pixel area is important for a competitive HRAM
- Compact, modular design using phase conjugate read-out
- Doubly-doped lithium niobate is a promising recording material